



(10) **Patent No.:** **US 7,777,825 B2**  
(45) **Date of Patent:** **Aug. 17, 2010**

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- (\*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 384 days.

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- (21) Appl. No.: **11/721,538**

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- (22) PCT Filed: **Dec. 13, 2005**

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- (86) PCT No.: **PCT/JP2005/022840**

Official Communication for PCT Application No. JP2005/022840;  
mailed on Feb. 21, 2006.

§ 371 (c)(1).

(2), (4) Date: **Jun. 13, 2007**

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- (87) PCT Pub. No.: **WO2006/064789**

(57) **ABSTRACT**

PCT Pub. Date: **Jun. 22, 2006**

- (65) **Prior Publication Data**

US 2009/0262274 A1      Oct. 22, 2009

- (30) **Foreign Application Priority Data**

Dec. 14, 2004 (JP) ..... 2004-360654

- (51) **Int. Cl.**  
**G02F 1/1333** (2006.01)

- (52) **U.S. Cl.** ..... 349/54; 345/90

- (58) **Field of Classification Search** ..... 345/90;  
349/38, 54

See application file for complete search history.

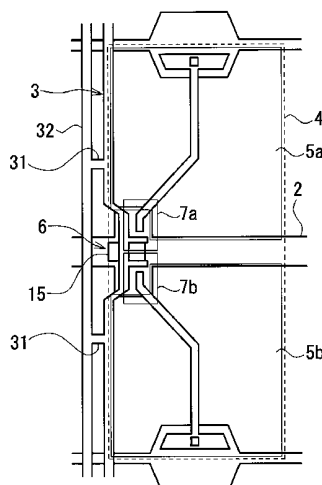
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### 6 Claims, 13 Drawing Sheets



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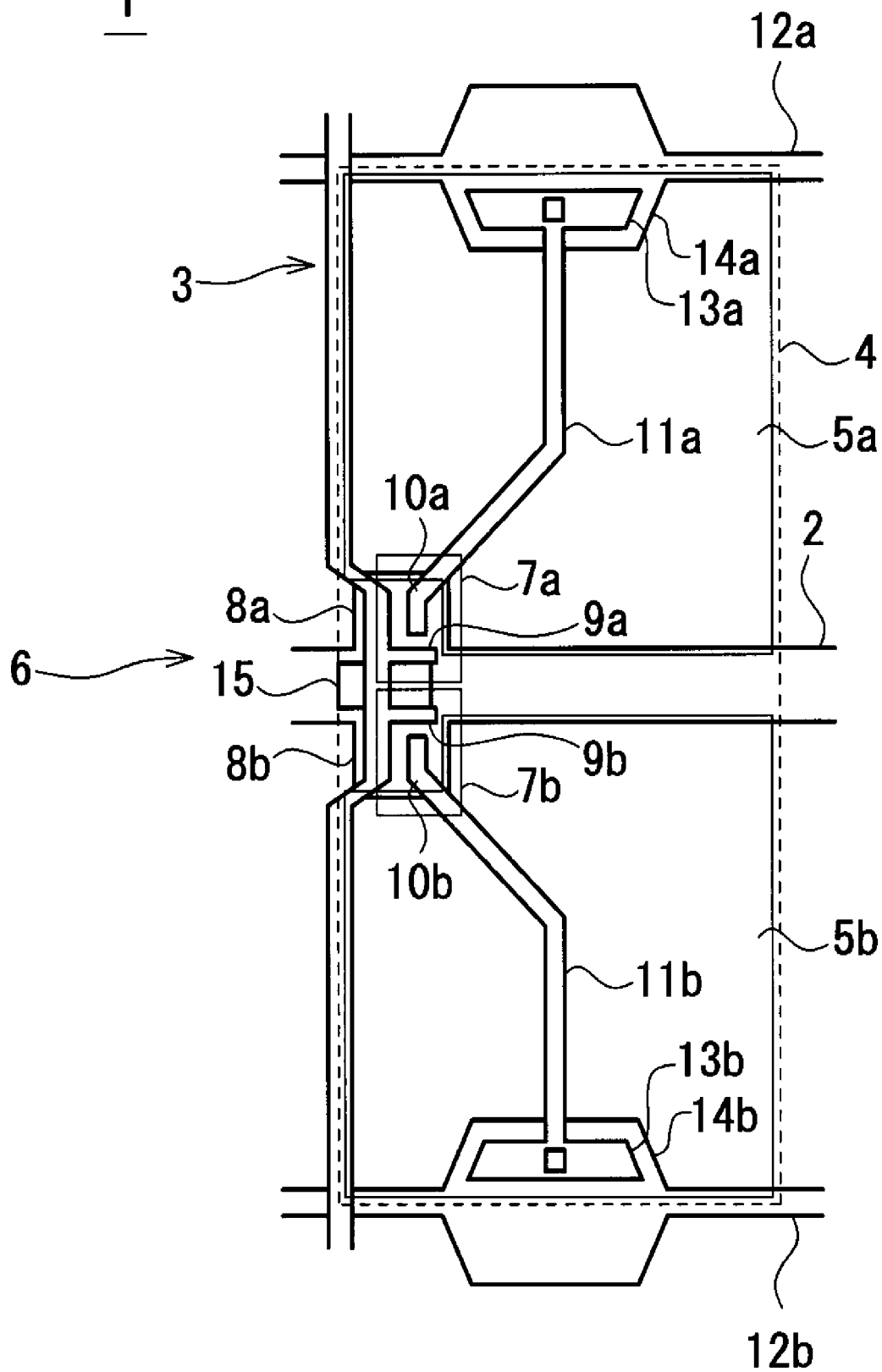
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**FIG. 1**

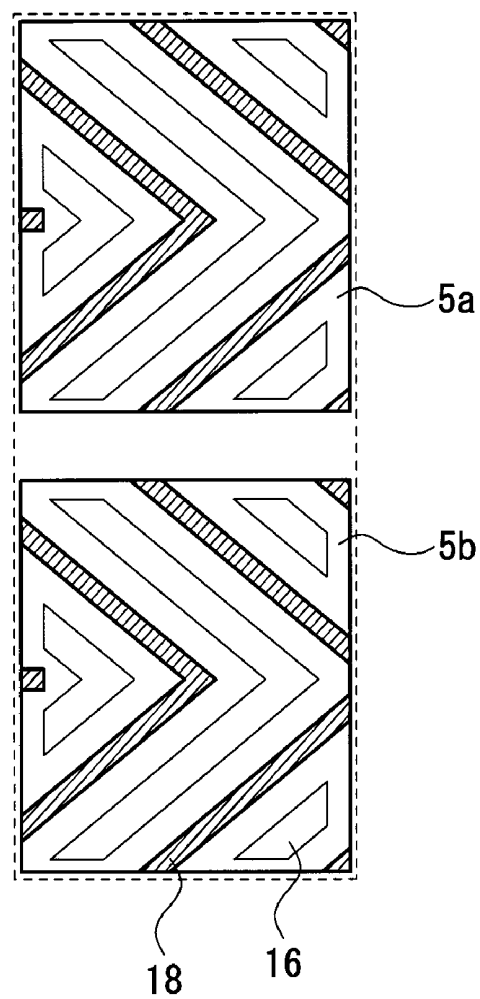


FIG. 2A

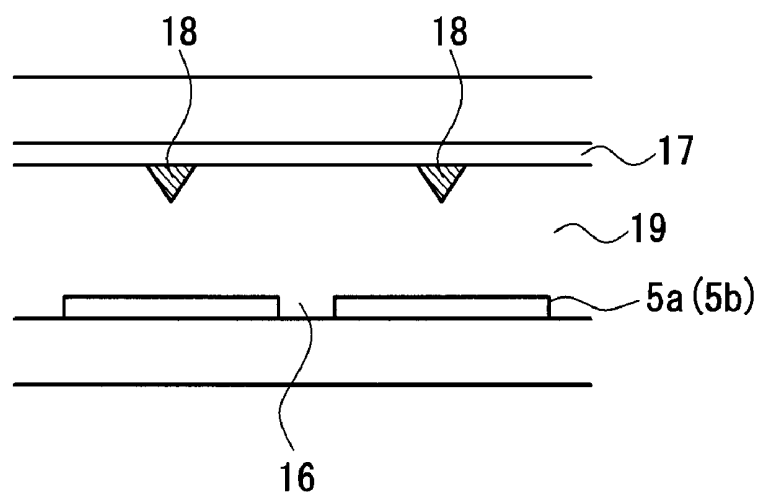


FIG. 2B

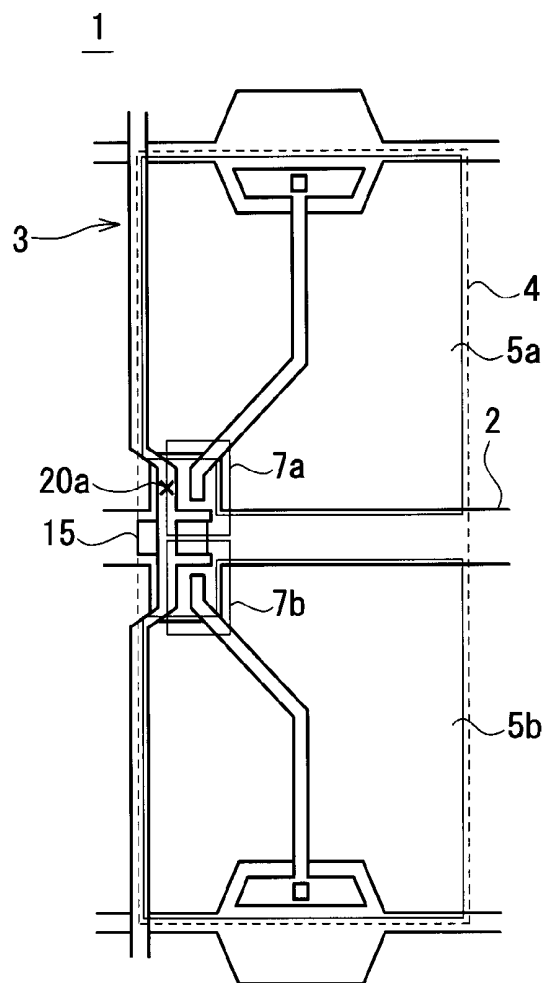


FIG. 3A

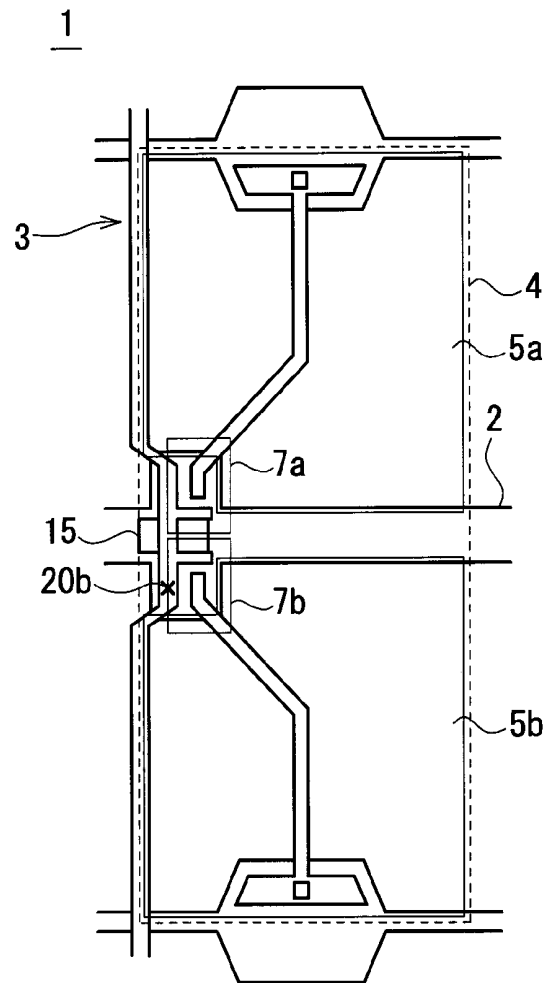


FIG. 3B

Input direction of source signal

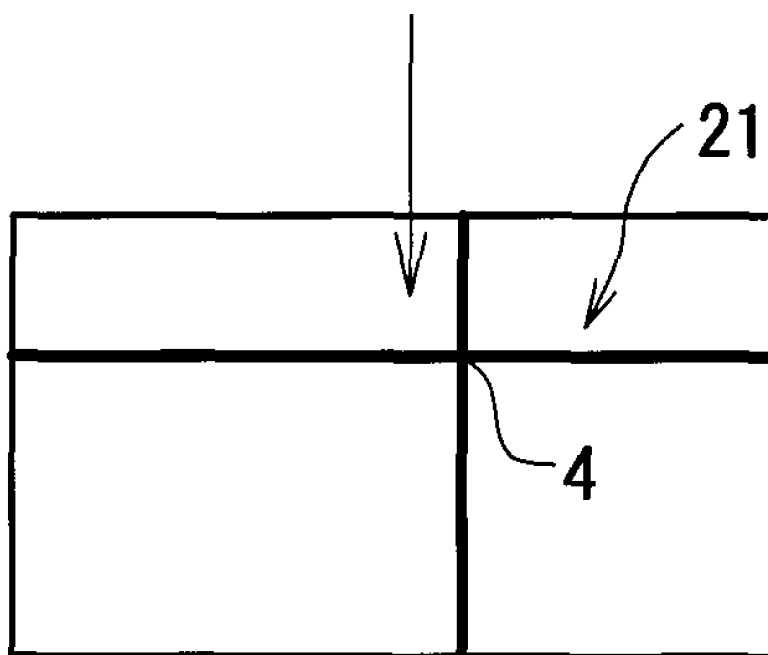


FIG. 4

**FIG. 5B**

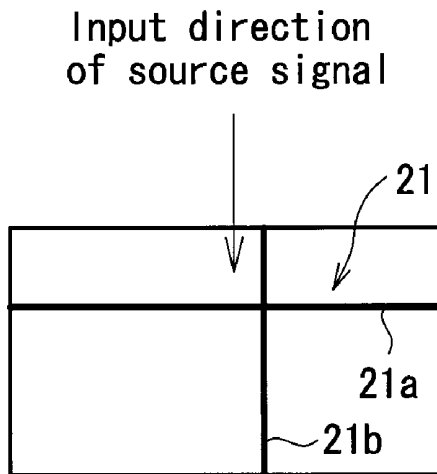


FIG. 6A

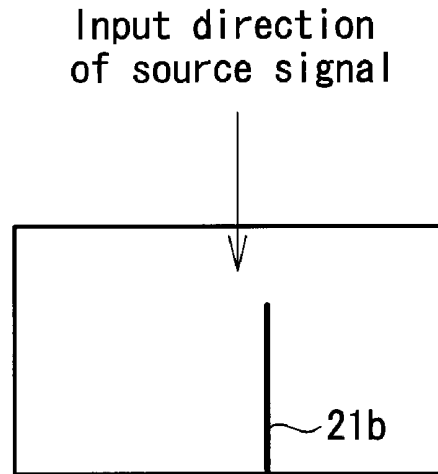


FIG. 6B

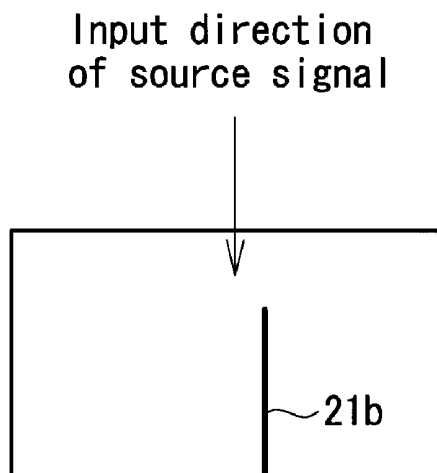


FIG. 7A

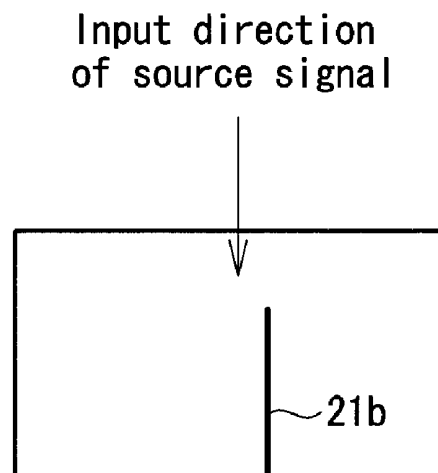


FIG. 7B



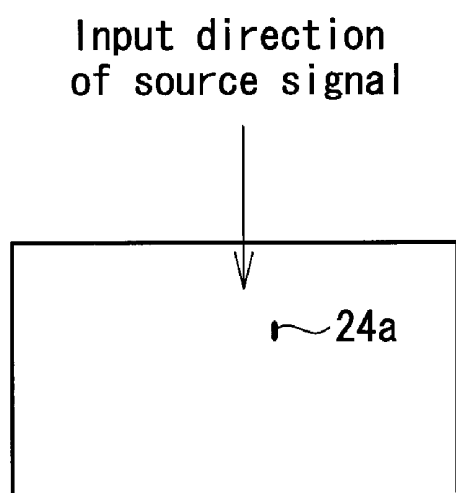


FIG. 8A

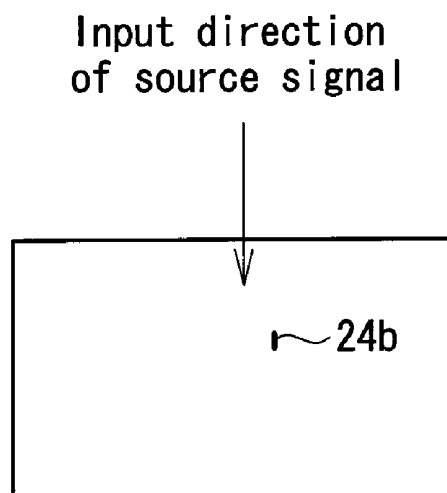


FIG. 8B

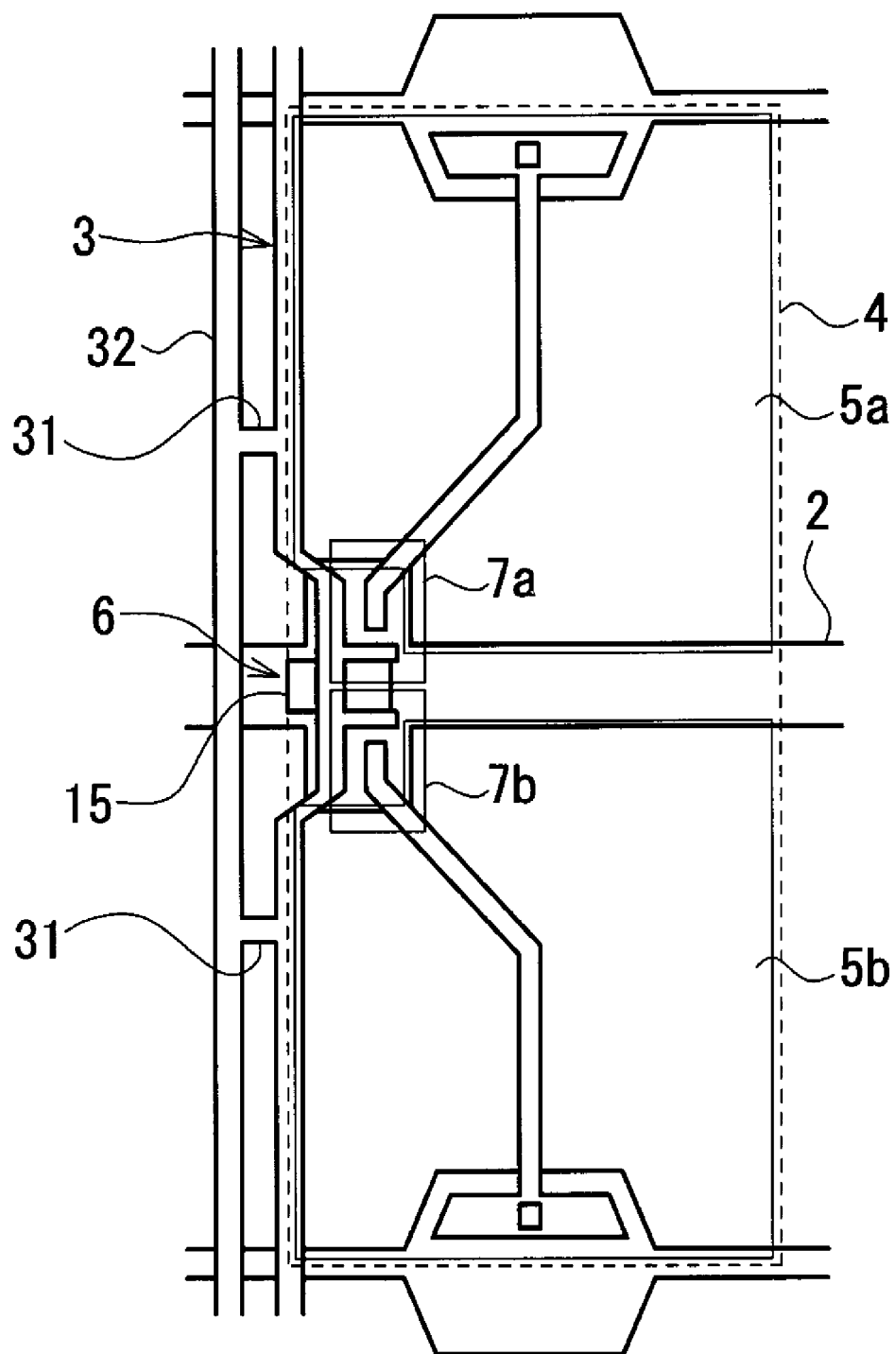
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FIG. 9

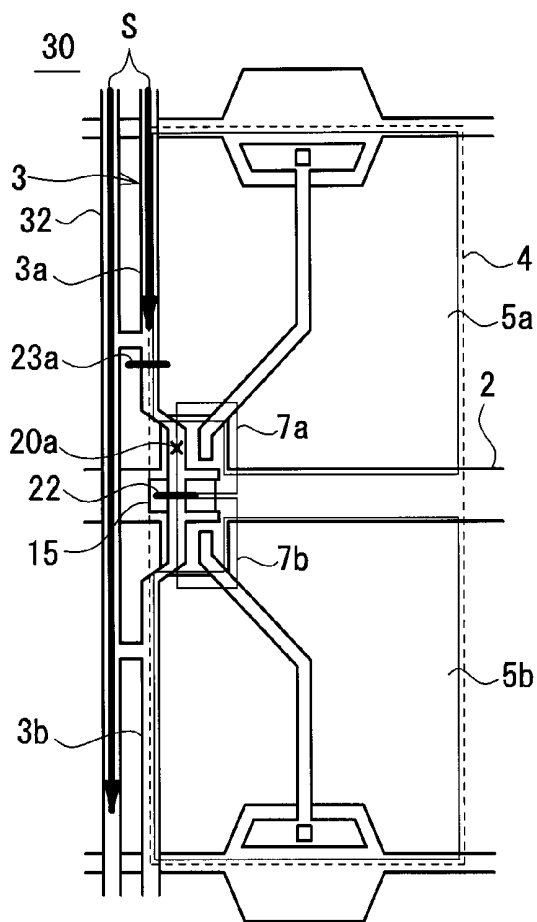


FIG. 10A

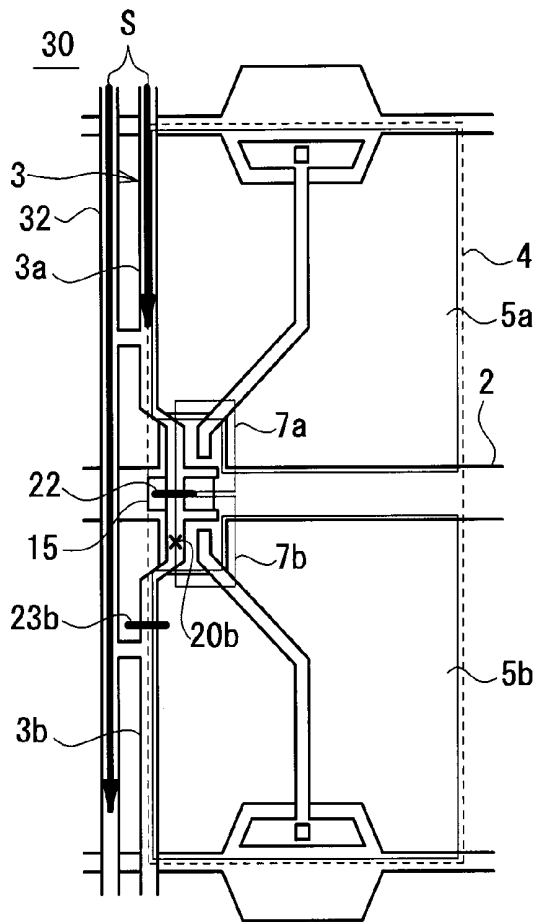


FIG. 10B

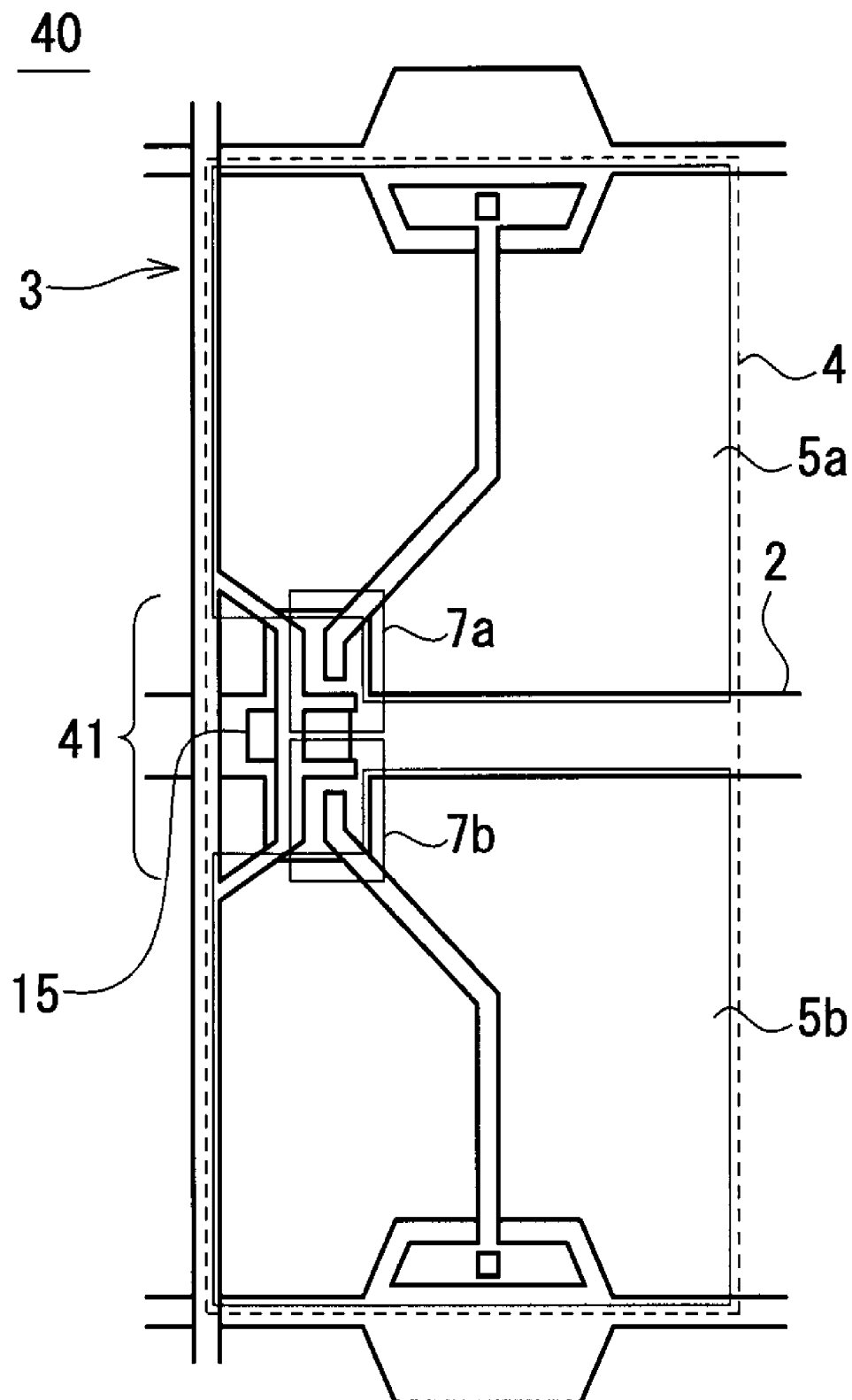


FIG. 11

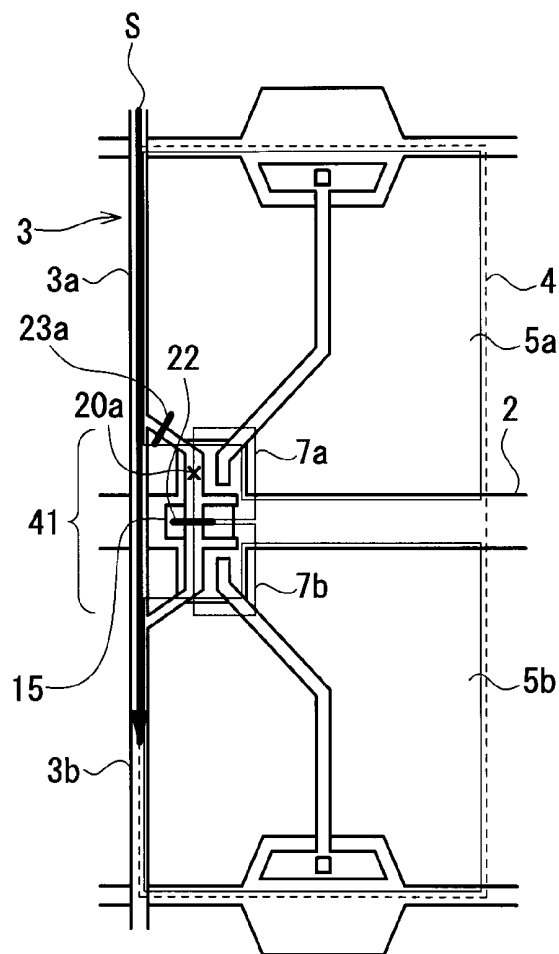


FIG. 12A

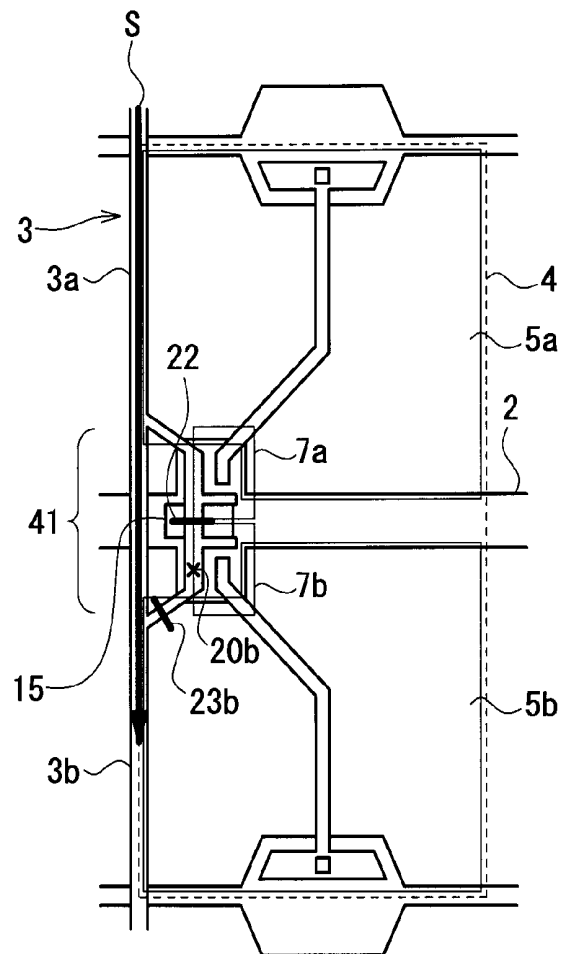
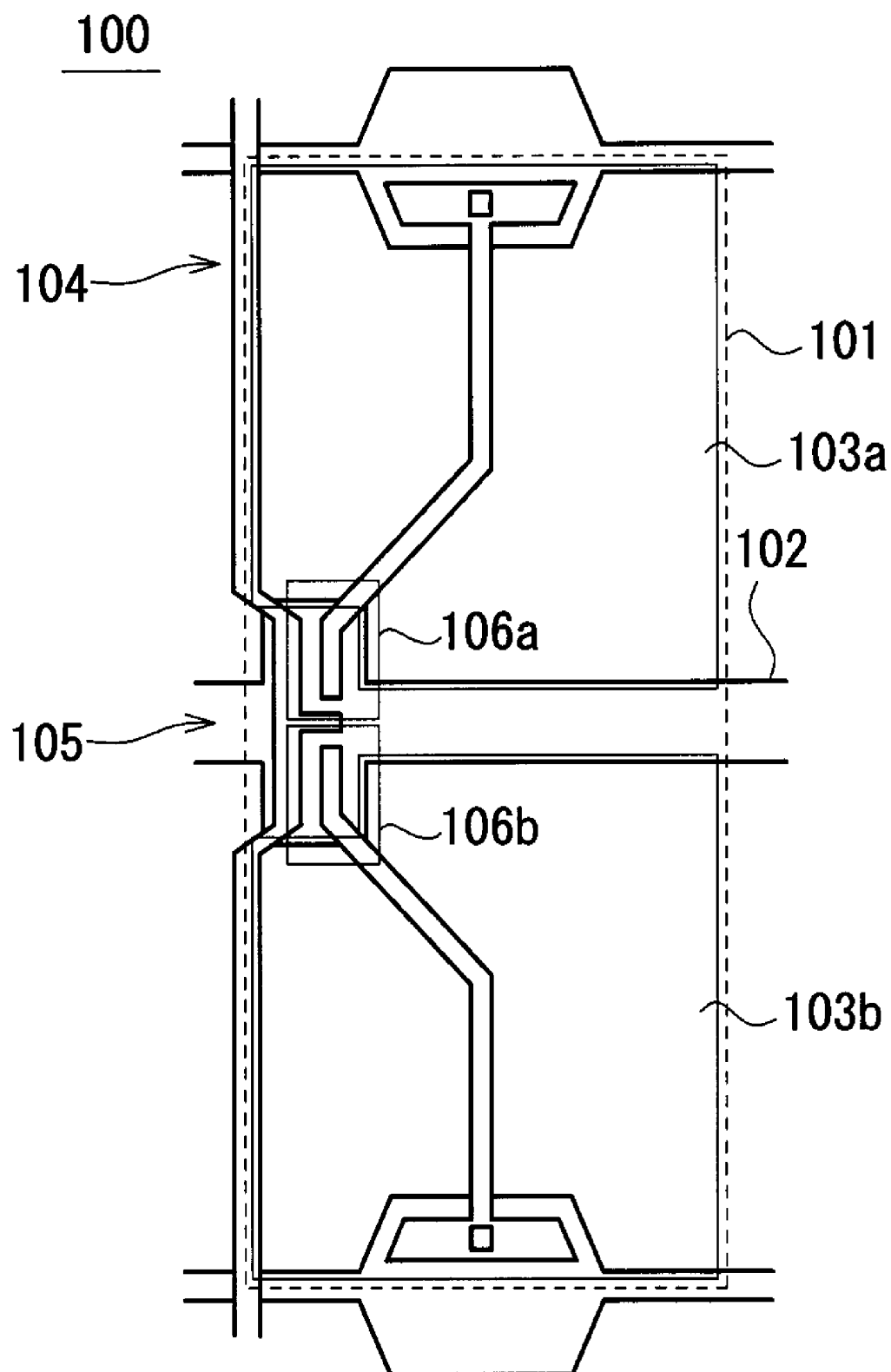


FIG. 12B



**FIG. 13**

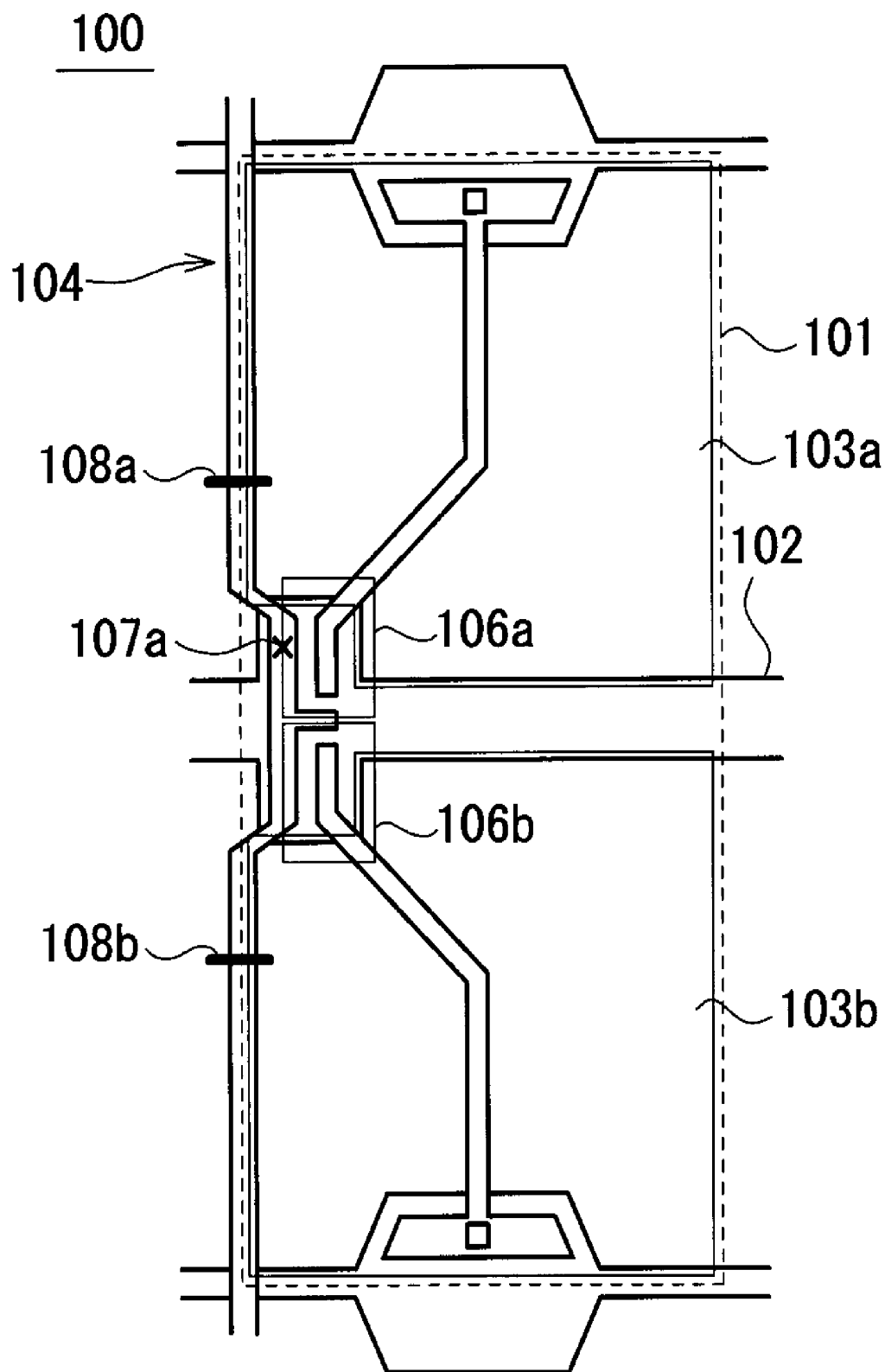


FIG. 14

# LIQUID CRYSTAL DISPLAY AND A DEFECT CORRECTING METHOD FOR THE SAME

## BACKGROUND OF THE INVENTION

### 1. Field of the Invention

The present invention relates to a liquid crystal display and a defect correcting method for the same, and more specifically relates to a liquid crystal display adopting a pixel division method and a defect correcting method for the same.

### 2. Description of the Related Art

A liquid crystal display has excellent characteristics such as high definition, thinness, lightness and low power consumption. Thus, recently, the liquid crystal display is rapidly expanding its market in accordance with an improvement in production capacity, an improvement in price competition with other displays, and the like.

For this kind of liquid crystal display, Japanese Patent Application Unexamined Publication No. 2004-78157, for example, discloses a liquid crystal display provided with an active matrix array substrate adopting a pixel division method in which each pixel electrode includes an assembly of a plurality of sub-pixel electrodes.

FIG. 13 is a schematic diagram showing a pixel electrode formed on an active matrix array substrate provided in a conventional liquid crystal display. Specifically, as shown in FIG. 13, a pixel electrode 101 on an active matrix array substrate 100 is split into sub-pixel electrodes 103a and 103b interposing a gate line 102 therebetween. In the vicinity of an intersection portion 105 of the gate line 102 and a source line 104, separate thin film transistors (TFTs) 106a and 106b which are driven by the common gate line 102 and the common source line 104 are provided, and the TFTs 106a and 106b are electrically connected to their corresponding sub-pixel electrodes 103a and 103b.

In the liquid crystal display provided with the above-mentioned active matrix array substrate 100, the common gate line 102 and the common source line 104 are used to drive the sub-pixel electrodes 103a and 103b via the separate TFTs 106a and 106b.

Therefore, for example, as shown in FIG. 14, when a leak 107a (hereinafter referred to as the "SG leak") is developed in the TFT 106a between the gate line 102 and the source line 104, and a correction for the SG leak 107a is performed using a correcting device such as a laser, it is necessary to cut the source line 104 at cut sections 108a and 108b to completely isolate the SG leak 107a from the source line 104. Consequently, even if the leak is developed only in the TFT 106a, the sub-pixel electrode 103b driven by the TFT 106b is unintentionally made defective.

In other words, there is a problem that even though the pixel division method in which each pixel electrode includes the assembly of the plurality of sub-pixel electrodes is adopted, a whole pixel unintentionally results in a defective pixel (for example, if the liquid crystal display uses a normally black mode, the defective pixel is observed as a full black dot of a whole pixel).

## SUMMARY OF THE INVENTION

In order to overcome the problems described above, preferred embodiments of the present invention provide a liquid crystal display adopting a pixel division method by which the size of a defect can be made smaller than conventional, and also provide a defect correcting method for the liquid crystal display.

According to a preferred embodiment the present invention, a liquid crystal display is provided with an active matrix array substrate including a plurality of gate lines and a plurality of source lines disposed on a transparent substrate to intersect with each other, and a plurality of pixel electrodes arranged in a matrix, each of the pixel electrodes including an assembly of a plurality of sub-pixel electrodes, separate active elements respectively connected to the sub-pixel electrodes in the vicinity of an intersection portion of the gate line and the source line, the active elements being driven by the common gate line and the common source line, and at least one opening portion being formed in a lower-layer side line placed in a lower layer at the intersection portion of the gate line and the source line.

In the above liquid crystal display, it is preferable that the lower-layer side line is the gate line, and an upper-layer side line which is placed in an upper layer of the lower-layer side line is the source line.

In addition, in the above liquid crystal display, it is preferable that an additional source line being partially connected to and extending along the source line is further included, or that a bypass line being connected to the source line at the intersection portion is included.

In addition, in the above liquid crystal display, it is preferable that the opening portion does not include an electrode layer and/or a semiconductor layer.

On the other hand, a defect correcting method for a liquid crystal display according to another preferred embodiment of the present invention is a defect correcting method for the above liquid crystal display, and includes at least the steps of cutting the upper-layer side line passing above the opening portion, and cutting a line including a defective section in the cut line so as to disconnect the defective section.

The liquid crystal display as mentioned above is provided with the active matrix array substrate in which the separate active elements, which are driven by the common gate line and the common source line, are respectively connected to their corresponding sub-pixel electrodes in the vicinity of the intersection portion of the gate line and the source line, and the opening portion is formed in the lower-layer side line at the intersection portion of the gate line and the source line.

Therefore, when a defect is developed in any one of the active elements and the like, the upper-layer side line passing above the opening portion can be easily cut by using a correcting mechanism such as a laser. If a line including the defective section in the cut line is cut, the defective section can be completely isolated from the line.

If correction using an auxiliary line and the like are made as necessary thereafter, the defect can be observed as a defective pixel of a sub-pixel, not as a defective pixel of a whole pixel. Thus, the size of the defective pixel is made smaller than conventional, leading to no defects. Consequently, when the active matrix array substrate is used especially in a comparatively large liquid crystal display and the like, advantages achieved include an improvement in display quality due to the reduction of the number of defects, an improvement in production efficiency (yields), and the like.

When the additional source line being partially connected to and extending along the source line is further included, the advantages described above can be obtained without making the correction using the auxiliary line. Therefore, there is an advantage that hours of work required for defect correction can be reduced to further improve the production efficiency of the liquid crystal display.

In addition, when the bypass line is connected to the source line in the intersection portion, an aperture area per pixel can be widely assured while maintaining certain redundancy as



mentioned above. Therefore, advantages including an improvement in display quality in accordance with an improvement in display luminance, cost reduction or reduction in power consumption of a backlight in accordance with an improvement in luminance efficiency, and the like, are achieved.

In addition, when the opening portion does not include the electrode layer and/or the semiconductor layer, there are advantages that a leak by the electrode layer and a cut piece produced during the line cutting by using the correcting mechanism such as the laser is not developed, and correction can be easily made.

On the other hand, according to the defect correcting method for the liquid crystal display according to another preferred embodiment of the present invention, by cutting the upper-layer side line passing above the opening portion, a judgment on whether the defective section is present in a line on an input-end side of the cut section or in a line on an open-end side of the cut section can be easily made through image display after the line cutting, and the defective section can be isolated from the line by cutting the line including the defective section.

Therefore, the defective section, which is conventionally hard to detect by a microscopic observation and the like, can be easily detected. Thus, the defect correcting method has an advantage of allowing for reliable correction.

Other features, elements, steps, characteristics and advantages of the present invention will become more apparent from the following detailed description of preferred embodiments with reference to the attached drawings.

#### BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a schematic diagram showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to a first preferred embodiment of the present invention.

FIGS. 2A and 2B are schematic diagrams showing a placement relationship between slits formed in the pixel electrode (sub-pixel electrodes) and ribs formed on a common electrode in the liquid crystal display according to the first preferred embodiment (in a multi-domain vertical alignment (MVA) mode).

FIGS. 3A and 3B are views showing positions of an SG leak which is developed in thin film transistors (TFTs) on the active matrix array substrate provided in the liquid crystal display according to the first preferred embodiment of the present invention.

FIG. 4 is a schematic diagram showing an image observed from a transparent substrate side of the active matrix array substrate when the SG leak shown in FIG. 3 is developed.

FIGS. 5A and 5B are views for explaining steps for making correction using an auxiliary line by cutting a source line above an opening portion, and then cutting a source line on an input side or a source line on a non-input side to isolate the SG leak.

FIGS. 6A and 6B are schematic diagrams showing images observed from the transparent substrate side of the active matrix array substrate when the source line above the opening portion is cut.

FIGS. 7A and 7B are schematic diagrams showing images observed from the transparent substrate side of the active matrix array substrate when the source line on the input side or the source line of the non-input side is cut to isolate the SG leak.

FIGS. 8A and 8B are schematic diagrams showing images observed from the transparent substrate side of the active matrix array substrate when the correction using the auxiliary line is made.

FIG. 9 is a schematic diagram showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to a second preferred embodiment of the present invention.

FIGS. 10A and 10B are views for explaining steps of cutting a source line above an opening portion, and then cutting a source line on an input side or a source line on a non-input side to isolate an SG leak in the liquid crystal display according to the second preferred embodiment of the present invention.

FIG. 11 is a schematic view showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to a third preferred embodiment of the present invention.

FIGS. 12A and 12B are views for explaining steps of cutting a source line above an opening portion, and then cutting a source line on an input side or a source line on a non-input side to isolate an SG leak in the liquid crystal display according to the third preferred embodiment of the present invention.

FIG. 13 is a schematic diagram showing an electrode substrate formed on an active matrix array substrate provided in a conventional liquid crystal display.

FIG. 14 is a view for explaining a defect correcting method when an SG leak is developed in any one of TFTs in the conventional liquid crystal display.

#### DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS

A detailed description of a liquid crystal display and a defect correcting method for the same according to preferred embodiments of the present invention will now be given.

In principle, the liquid crystal display according to preferred embodiments of the present invention is a device in which at least a driving circuit which controls alignment of liquid crystals based on an external signal is attached to a liquid crystal panel in which the liquid crystals are sealed in between an active matrix array substrate having at least a plurality of pixel electrodes and a plurality of active elements on a transparent substrate and a substrate having at least a common electrode for the plurality of pixel electrodes on a transparent common substrate opposed to the transparent substrate, where information can be displayed by conducting optical modulation.

The liquid crystal display is characterized in that the active matrix array substrate has a new structure. Accordingly, the structure of the active matrix array substrate provided in the liquid crystal display according to the preferred embodiments of the present invention will be mainly described hereinafter.

On the other hand, the defect correcting method for the liquid crystal display according to a preferred embodiment of the present invention is a method for correcting a defect by utilizing the new structure of the active matrix array substrate provided in the liquid crystal display according to a preferred embodiment of the present invention. Therefore, the defect

correcting method will be described with respect to each of liquid crystal displays according to preferred embodiments of the present invention.

#### First Preferred Embodiment

FIG. 1 is a schematic diagram showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to a first preferred embodiment of the present invention.

On a transparent substrate (unillustrated) constituting the active matrix array substrate 1, a plurality of gate lines 2 extending in a row direction are formed, and a plurality of source lines 3 extending in a column direction are formed while intersecting at right angles with the gate lines 2 via an insulating layer (unillustrated). Incidentally, the gate line 2 shown in FIG. 1 is the  $n^{\text{th}}$  one, and the source line 3 shown in FIG. 1 is the  $m^{\text{th}}$  one. In addition, the gate line 2 is a lower-layer side line, and the source line 3 is an upper-layer side line.

A pixel electrode 4 is split into two sub-pixel electrodes 5a and 5b interposing the gate line 2 therebetween. In the vicinity of an intersection portion 6 of the gate line 2 and the source line 3, separate thin film transistors (TFTs) 7a and 7b which are respectively connected to the sub-pixel electrodes 5a and 5b are provided.

The TFTs 7a and 7b are on/off controlled by a scanning signal voltage provided by gate electrodes 8a and 8b connected to the common gate line 2. In addition, a display signal voltage provided by source electrodes 9a and 9b connected to the common source line 3 is provided to the sub-pixel electrodes 5a and 5b via drain lines 11a and 11b extending from drain electrodes 10a and 10b.

In the drain lines 11a and 11b, portions opposed to auxiliary capacitance lines 12a and 12b, which are placed parallel to the gate line 2, via the insulating layer (unillustrated) function as auxiliary capacitance electrodes 13a and 13b. In addition, in the auxiliary capacitance lines 12a and 12b, portions opposed to the auxiliary capacitance electrode 13a and 13b via the insulating layer function as auxiliary capacitance common electrodes 14a and 14b.

At the intersection portion 6 of the gate line 2 and the source line 3, at least one opening portion 15 is formed in the gate line 2 being the lower-layer side line. Here, it is preferable that the opening portion 15 does not include an electrode layer and/or a semiconductor layer and the like. In other words, it is preferable that the opening portion 15 does not include constituent elements other than the upper-layer side line.

If the opening portion 15 does not include the electrode layer and/or the semiconductor layer, a leak and the like by a cut piece and the electrode layer are hard to be developed at the time of cutting a line using a correcting mechanism such as a laser, and correction can be easily made. Specific examples of the electrode layer and the semiconductor layer include ITO, an  $n^+/\text{i}$  layer and the like for the upper layer.

In the liquid crystal display according to the first preferred embodiment (also in the other preferred embodiments to be described later), it is preferable that slits 16 (portions which do not include the electrode layer) are formed in the sub-pixel electrodes 5a and 5b, and ribs 18 are formed on the common electrode 17, as schematically shown in FIGS. 2A and 2B, and nematic liquid crystals having negative dielectric anisotropy are used as liquid crystals 19. This is because liquid crystal molecules are aligned in multiple directions by the action of the slits 16 and the ribs 18 at the time of application of an electric field, so that a favorable wide viewing angle can be obtained.

Next, a defect correcting method for the liquid crystal display according to the first preferred embodiment will be described referring to FIGS. 3A to 8B.

When an SG leak 20a in the TFT 7a or an SG leak 20b in the TFT 7b is developed between the gate line 2 and the source line 3 as shown in FIGS. 3A and 3B, observation by lighting of a liquid crystal panel shows that a cross defect 21 having an intersection point at the pixel electrode 4 is developed in an image viewed from the transparent substrate side of the active matrix array substrate 1, as shown in FIG. 4. Incidentally, at this point in time, it is uncertain which of the SG leak 20a in the TFT 7a or the SG leak 20b in the TFT 7b is developed. In other words, it is uncertain which of a state in FIG. 3A or a state in FIG. 3B is brought about.

Then, as shown in FIGS. 5A and 5B, the source line 3 being the upper-layer side line passing above the opening portion 15 is cut at a cut section 22 from the transparent substrate side by using the correcting mechanism such as the laser, and the observation by lighting of the liquid crystal panel is made again.

In the observation, if the SG leak 20a in the TFT 7a on an input-end side (hereinafter referred to as the "input side") of the cut section 22 of the source line 3 is developed as shown in FIG. 5A, the cross defect 21 is still observed as shown in FIG. 6A. On the other hand, if the SG leak 20b in the TFT 7b on an open-end side (hereinafter referred to as the "non-input side") of the cut section 22 of the source line 3 is developed as shown in FIG. 5B, a line defect 21a in the direction of the gate line 2 disappears and a line defect 21b in the direction of the source line 3 is observed as shown in FIG. 6B.

Shortly, by cutting the source line 3 passing above the opening portion 15 at the cut section 22, a judgment on which of the SG leak 20a in the TFT 7a or the SG leak 20b in the TFT 7b is developed is facilitated. Accordingly, it becomes possible to judge which part of the cut line (a source line 3a on the input side or a source line 3b on the non-input side) is to be cut in the subsequent step.

Then, if the SG leak 20a in the TFT 7a is developed as shown in FIG. 5A, the source line 3a on the input side is cut at a cut section 23a to completely isolate the SG leak 20a from the source line 3. In this case, in the image of the observation by lighting, the line defect 21a in the direction of the gate line 2 disappears, and the line defect 21b in the direction of the source line 3 is observed, as shown in FIG. 7A.

On the other hand, if the SG leak 20b in the TFT 7b is developed as shown in FIG. 5B, the source line 3b on the non-input side is cut at a cut section 23b to completely isolate the SG leak 20b from the source line 3. In this case, in the image of the observation by lighting, the line defect 21b in the direction of the source line 3 is still observed as shown in FIG. 7B.

Next, in a case where the SG leak 20a in the TFT 7a is developed as shown in FIG. 5A, by making correction using an auxiliary line (a redundancy line) (unillustrated) and inputting a source signal S' via the auxiliary line from the source line 3b on the non-input side to the TFT 7b, a sub-pixel (the sub-pixel electrode 5b) can be driven. On the other hand, in a case where the SG leak 20b in the TFT 7b is developed as shown in FIG. 5B, by performing the correction using the auxiliary line and inputting the source signal S' (unillustrated) from the source line 3b on the non-input side, sub-pixels (pixels) (unillustrated) arranged on the non-input side of the sub-pixel (the sub-pixel electrode 5b) can be driven.

Therefore, for example, if the liquid crystal display according to the first preferred embodiment uses a normally black mode, the defective pixel is observed as not a full black dot of a whole pixel but a half black dot 24a or 24b of a sub-pixel as

shown in FIGS. 8A and 8B. In addition, for example, if the liquid crystal display according to the first preferred embodiment uses a normally white mode, the defective pixel is observed as a half bright dot of a sub-pixel, and by performing processing such as forming it into a black dot, the defective pixel is observed as a half black dot **24a** or **24b** of a sub-pixel. In either case, the size of the defective pixel is made smaller than conventional, leading to a state of no defect (a normal level in view of display quality can be attained), so that quality of the liquid crystal display is improved.

For the correction using the auxiliary line, a known method can be used (see, for example, Japanese Patent Application Unexamined Publication Nos. Hei5-203986 and Hei9-146121).

Specifically, an auxiliary line (unillustrated) is placed in a peripheral portion of a display region on the active matrix array substrate **1** so as to extend completely around or extend half-way around the display region, and an input end and an open end of the source line **3** are short-circuited by the auxiliary line.

#### Second Preferred Embodiment

FIG. 9 is a schematic view showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to a second preferred embodiment of the present invention.

The structure of the active matrix array substrate **30** provided in the liquid crystal display according to the second preferred embodiment is basically the same as the structure of the active matrix array substrate **1** provided in the liquid crystal display according to the first preferred embodiment except for the source line **3**. Therefore, differences from the liquid crystal display and the defect correcting method for the same according to the first preferred embodiment will be mainly described hereinafter.

As shown in FIG. 9, in the active matrix array substrate **30** provided in the liquid crystal display according to the second preferred embodiment, an additional source line **32** is further included while being partially connected to the source line **3** via connecting portions **31** and extending along the source line **3**.

In the liquid crystal display according to the second preferred embodiment as mentioned above, when the SG leak **20a** in the TFT **7a** or the SG leak **20b** in the TFT **7b** is developed as shown in FIGS. 10A and 10B, similarly to the first preferred embodiment, the source line **3** being the upper-layer side line passing above the opening portion **15** is cut at the cut section **22** from the transparent substrate side by using the correcting mechanism such as the laser for correcting the SG leak **20a** or the SG leak **20b**.

Accordingly, a judgment on which of the SG leak **20a** in the TFT **7a** or the SG leak **20b** in the TFT **7b** is developed can be easily made based on an image viewed from the transparent substrate side. Then, if the SG leak **20a** in the TFT **7a** is developed as shown in FIG. 10A, the source line **3a** on the input side is cut at the cut section **23a** to completely isolate the SG leak **20a** from the source line **3**.

Here, as the active matrix array substrate **30** provided in the liquid crystal display according to the second preferred embodiment has the additional source line **32**, a source signal S from the input side is inputted to the TFT **7b** via the additional source line **32**. Accordingly, the sub-pixel (the sub-pixel electrode **5b**) can be driven without making the correction using the auxiliary line.

On the other hand, if the SG leak **20b** in the TFT **7b** is developed as shown in FIG. 10B, the source line **3b** on the non-input side is cut to completely isolate the SG leak **20b** from the source line **3**.

Accordingly, the source signal S from the input side is supplied also to the non-input side via the additional source line **32**. Thus, the sub-pixels (pixels) placed on the non-input side of the sub-pixel (the sub-pixel electrode **5b**) can be driven without making the correction using the auxiliary line.

Consequently, also owing to the liquid crystal display according to the second preferred embodiment, the defect can be observed as a defective pixel of a sub-pixel, not as a defective pixel of a whole pixel, and the size of the defective pixel is made smaller than conventional, leading to no defects.

In addition, in the liquid crystal display according to the second preferred embodiment, there is no need to make the correction using the auxiliary line. As a result, hours of work required for defect correction can be reduced to improve production efficiency of the liquid crystal display. Further, delay of the source signal due to the correction using the auxiliary line and the like in the case of a large liquid crystal display can be avoided.

#### Third Preferred Embodiment

FIG. 11 is a schematic diagram showing a pixel electrode formed on an active matrix array substrate provided in a liquid crystal display according to the third preferred embodiment.

The structure of the active matrix array substrate **40** provided in the liquid crystal display according to the third preferred embodiment is also basically the same as the structure of the active matrix array substrate **1** provided in the liquid crystal display according to the first preferred embodiment except for the source line **3**. Therefore, differences from the liquid crystal display and the defect correcting method for the same according to the first preferred embodiment will be mainly described hereinafter.

As shown in FIG. 11, in the active matrix array substrate **40** provided in the liquid crystal display according to the third preferred embodiment, a bypass line **41** is included in the vicinity of the opening portion **15** of the source line **3**. In this preferred embodiment, an example of this preferred embodiment where the bypass line **41** does not pass above the opening portion **15** is illustrated. However, the bypass line **41** may pass above the opening portion **15**.

In the liquid crystal display according to the third preferred embodiment as mentioned above, when the SG leak **20a** in the TFT **7a** or the SG leak **20b** in the TFT **7b** is developed as shown in FIGS. 12A and 12B, similarly to the first and second preferred embodiments, the source line **3** being the upper-layer side line passing above the opening portion **15** is cut at the cut section **22** from the transparent substrate side by using the correcting mechanism such as the laser for correcting the SG leak **20a** or the SG leak **20b**.

Accordingly, a judgment on which of the SG leak **20a** in the TFT **7a** or the SG leak **20b** in the TFT **7b** is developed can be easily made based on an image viewed from the transparent substrate side. Thereafter, if the SG leak **20a** in the TFT **7a** is developed as shown in FIG. 12A, the source line **3a** on the input side is cut at the cut section **23a** to completely isolate the SG leak **20a** from the source line **3**.

Here, as the active matrix array substrate **40** provided in the liquid crystal display according to the third preferred embodiment has the bypass line **41**, the source signal S from the input side is inputted to the TFT **7b** via the bypass line **41**. Accordingly, the sub-pixel (the sub-pixel electrode **5b**) can be driven without making the correction using the auxiliary line.

On the other hand, if the SG leak **20b** in the TFT **7b** is developed as shown in FIG. **12B**, the source line **3b** on the non-input side is cut to completely isolate the SG leak **20b** from the source line **3**.

Thus, the source signal **S** from the input side is supplied also to the non-input side via the bypass line **41**. Accordingly, the sub-pixels (pixels) placed on the non-input side of the sub-pixel (the sub-pixel electrode **5b**) can be driven without making the correction using the auxiliary line.

Consequently, also according to the liquid crystal display according to the third preferred embodiment, the defect can be observed as a defective pixel of a sub-pixel, not as a defective pixel of a whole pixel, and the size of the defective pixel is made smaller than conventional, leading to no defects. In addition, the liquid crystal display according to the third preferred embodiment has equal redundancy to the liquid crystal display according to the second preferred embodiment.

Further, in the liquid crystal display according to the third preferred embodiment, an aperture area per pixel can be widely assured, which enables an improvement in display quality in accordance with an improvement in display luminance, cost reduction or reduction in power consumption of a backlight in accordance with an improvement in luminance efficiency, and the like.

The foregoing descriptions of the preferred embodiments of the present invention are not intended to be exhaustive or to limit the present invention to the precise form disclosed, and modifications and variations are possible in the light of the above teachings or may be acquired from practice of the present invention.

While the descriptions have been made to cases where each of the pixel electrodes includes the assembly of two sub-pixel electrodes in the above-described preferred embodiments, it is also preferable that each of the pixel electrodes includes an assembly of three or more sub-pixel electrodes.

In addition, while the descriptions have been made with reference to examples of preferred embodiments where the gate line is the lower-layer side line and the source line is the upper-layer side line, it is also preferable that the gate line is the upper-layer side line and the source line is the lower-layer side line.

Incidentally, while the descriptions have been made of examples of preferred embodiments where the TFTs are preferably used as the active elements, any elements which function as a switching element such as a metal insulator metal (MIM) may be used.

While preferred embodiments of the present invention have been described above, it is to be understood that variations and modifications will be apparent to those skilled in the art without departing the scope and spirit of the present invention. The scope of the present invention, therefore, is to be determined solely by the following claims.

What is claimed is:

1. A liquid crystal display provided with an active matrix array substrate, the active matrix array substrate comprising:
  - a plurality of gate lines and a plurality of source lines arranged on a transparent substrate so as to intersect with each other; and
  - a plurality of pixels arranged in a matrix, each of the plurality of pixels including:
    - a plurality of sub-pixel electrodes arranged such that one of the plurality of gate lines or one of the plurality of

source lines is interposed between corresponding ones of the plurality of sub-pixel electrodes;

a plurality of active elements that are respectively connected to a corresponding one of the plurality of sub-pixel electrodes in the vicinity of an intersection portion of corresponding ones of the plurality of gate lines and the plurality of source lines, the plurality of active elements being arranged to be driven by a same one of the plurality of source lines and a same one of the plurality of gate lines; and

at least one opening portion defined within a lower-layer side line located in a lower layer at the intersection portion of the corresponding ones of the plurality of gate lines and the plurality of source lines such that the opening portion is surrounded by the lower-layer side line.

2. The liquid crystal display according to claim 1, wherein the lower-layer side line is the gate line, and an upper-layer side line which is located in an upper layer of the lower-layer side line is the source line.

3. The liquid crystal display according to claim 1, further comprising an additional source line being partially connected to and extending along the source line.

4. The liquid crystal display according to claim 1, further comprising a bypass line being connected to the source line at the intersection portion.

5. The liquid crystal display according to claim 1, wherein the opening portion does not include at least one of an electrode layer and a semiconductor layer.

6. A defect correcting method for a liquid crystal display, comprising at least the steps of:

providing a liquid crystal display including:

an active matrix array substrate including:

a plurality of gate lines and a plurality of source lines arranged on a transparent substrate so as to intersect with each other;

a plurality of pixels arranged in a matrix, each of the plurality of pixels including:

a plurality of sub-pixel electrodes arranged such that one of the plurality of gate lines or one of the plurality of source lines is interposed between corresponding ones of the plurality of sub-pixel electrodes;

a plurality of active elements that are respectively connected to a corresponding one of the plurality of sub-pixel electrodes in the vicinity of an intersection portion of corresponding ones of the plurality of gate lines and the plurality of source lines, the plurality of active elements being arranged to be driven by a same one of the plurality of source lines and a same one of the plurality of gate lines; and

at least one opening portion defined within a lower-layer side line located in a lower layer at the intersection portion of the corresponding ones of the plurality of gate lines and the plurality of source lines such that the opening portion is surrounded by the lower-layer side line;

cutting an upper-layer side line passing above the opening portion; and

cutting a line including a defective section in the cut line to isolate the defective section.

\* \* \* \* \*

专利名称(译)	液晶显示器及其缺陷校正方法		
公开(公告)号	<a href="#">US7777825</a>	公开(公告)日	2010-08-17
申请号	US11/721538	申请日	2005-12-13
[标]申请(专利权)人(译)	夏普株式会社		
申请(专利权)人(译)	夏普株式会社		
当前申请(专利权)人(译)	夏普株式会社		
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发明人	NODA, TOMOKI TSUBATA, TOSHIHIDE TAKEUCHI, MASANORI ENDA, KENJI		
IPC分类号	G02F1/1333		
CPC分类号	G02F1/134309 G02F1/1368 G02F1/1309 G02F2001/136263 G02F2201/508		
优先权	2004360654 2004-12-14 JP		
其他公开文献	US20090262274A1		
外部链接	<a href="#">Espacenet</a> <a href="#">USPTO</a>		

#### 摘要(译)

液晶显示器使用像素分割方法，其可以比常规可能地减少缺陷的尺寸，以及用于液晶显示器的缺陷校正方法。液晶显示器具有有源矩阵阵列基板，该有源矩阵阵列基板包括多条栅极线和多条源极线，多条源极线排列在透明基板上以彼此交叉，多个像素电极排列成矩阵，每个像素电极包括多个子像素电极的组件，分别连接到栅极线和源极线的交叉部分附近的子像素电极的TFT，TFT由公共栅极线和公共源极线，并且至少一个开口部分形成在位于交叉部分处的下层中的下层侧线中。

